

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of)	
	Toshiki Makimoto, et al.)	
Serial No.:	10/516,380)	Art Unit
)	2818
Filing Date:	November 30, 2004)	
Confirmation No.:	2860)	
For:	P-TYPE NITRIDE SEMICONDUCTOR)	
	STRUCTURE AND BIPOLAR TRANSISTOR)	
Examiner:	Tram Hoang Nguyen)	

AMENDMENT "F" AND RESPONSE TO FINAL OFFICE ACTION

Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Sir:

Applicant submits this paper in response to the final Office Action mailed June 1, 2009.
Reconsideration is respectfully requested in view of the following remarks:

Remarks begin on page 2 of this paper.